

HIGH-POWER PNP SILICON POWER TRANSISTORS

...designed for use in general-purpose amplifier and switching application .

FEATURES:

- * Recommend for 150W High Fiderity Audio Frequency Amplifier Output stage
- * Complementary to 2SC2922

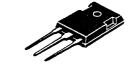
PNP 2SA1216

17 AMPERE POWER TRANASISTOR

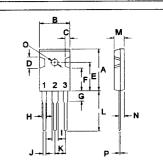
180 VOLTS 200 WATTS

MAXIMUM RATINGS

Characteristic	Symbol	2SA1216	Unit
Collector-Emitter Voltage	V _{CEO}	180	V
Collector-Base Voltage	V _{CBO}	180	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current - Continuous - Peak	I _C	17 20	А
Base current	I _B	5.0	А
Total Power Dissipation @T _C = 25°C Derate above 25°C	P _D	200 1.6	W/°C
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-55 to +150	°C



TO-247(3P)

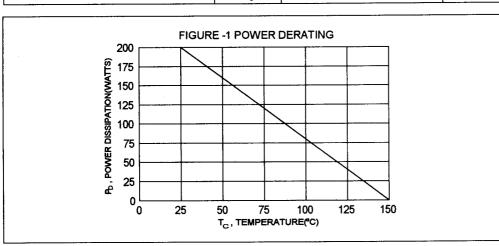


PIN 1.BASE 2.COLLECTOR 3.EMITTER

DIM	MILLIMETERS			
DIM	MIN	MAX		
Α	20.63	22.38		
В	15.38	16.20		
С	1.90	2.70		
D	5.10	6.10		
E	14.81	15.22		
F	11.72	12.84		
G	4.20	4.50		
Н	1.82	2.46		
1	2.92	3.23		
J	0.89	1.53		
Κ	5.26	5.66		
L	18.50	21.50		
´М	4.68	5.36		
N	2.40	2.80		
0	3.25	3.65		
Р	0.55	0.70		

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rθjc	0.625	°C/W



ELECTRICAL CHARACTERISTICS (T _c =	25°C unless otherwise noted)
--	------------------------------

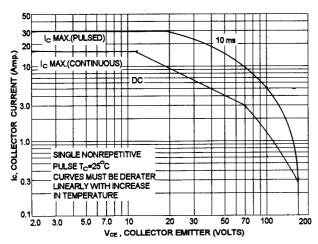
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (I _C = 25 mA, I _B = 0)	V _{(BR)CEO}	180		V
Collector Cutoff Current (V _{CB} = 180 V, I _E = 0)	Ісво		100	uA
Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0)	I _{EBO}		100	uA
ON CHARACTERISTICS (1)				
DC Current Gain (I _C = 8.0 A, V _{CE} = 4.0 V)	hFE	20		
Collector-Emitter Saturation Voltage (I _C = 8.0 A, I _B = 800 mA)	V _{CE(sat)}		2.0	٧
DYNAMIC CHARACTERISTICS				
Current-Gain-Bandwidth Product	f _T	10		MHz

SWITCHING CHARATERISTICS

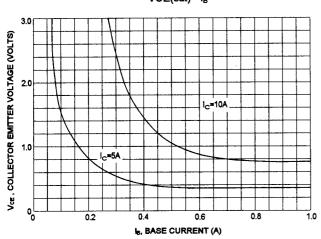
Turn-on Time	V _{cc} = 40 V, I _c = 10 A	t on	0.25(typ)	us
Storage Time	I _{B1} = -I _{B2} = 1.0 A R₁ = 4 ohm	ts	0.90(typ)	us
Fall Time	KL- 4 Ollili	t	0.30(typ)	us

⁽¹⁾ Pulse Test: Pulse Width =300 us,Duty Cycle ≦ 2.0%

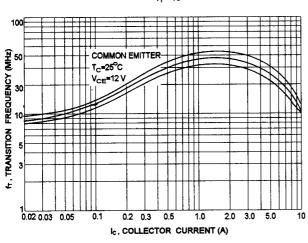
ACTIVE-REGION SAFE OPERATING AREA (SOA)



VCE(sat) - I_B



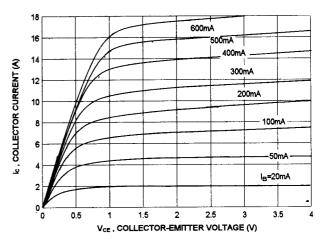
f_T - lc



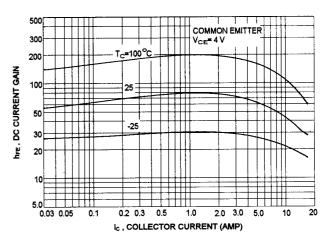
There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate $I_{\text{C}^-}V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on $T_{J(PK)}$ =150 °C; T_C is variable depending on conditions, second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)}$ ≤150°C,At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.





DC CURRENT GAIN





Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life (atomic energy control, aeronautics, traffic control, combustion control, safety devices etc.)